4.5 Ω High Bandwidth, Dual SPDT Analog Switch

The NLAS4717EP is an advanced CMOS analog switch fabricated in sub-micron silicon gate CMOS technology. The device is a dual independent Single Pole Double Throw (SPDT) switch featuring low $R_{DS(on)}$ of 4.5 Ω at 3.0 V.

The device also features guaranteed Break–Before–Make (BBM) switching, assuring the switches never short the driver.

The NLAS4717EP is available in two small size packages: Microbump: 2.0 x 1.5 mm WOFN-10: 1.4 x 1.8 mm

Features

- Low R_{DS(on)}: 4.5 Ω @ 3.0 V
- Matching Between the Switches $\pm 0.5 \Omega$
- Wide Voltage Range: 1.8 V to 5.5 V
- High Bandwidth > 90 MHz
- 1.65 V to 5.5 V Operating Range
- Low Threshold Voltages on Pins 4 and 8 (CTRL Pins)
- Ultra-Low Charge Injection $\leq 6.0 \text{ pC}$
- Low Standby Current: $I_{CC} = 1.0 \text{ nA} (Max) @ T_A = 25^{\circ}C$
- *OVT on Pins 4 and 8 (CTRL Logic Pins)
- These are Pb-Life Levices

Typical Applications

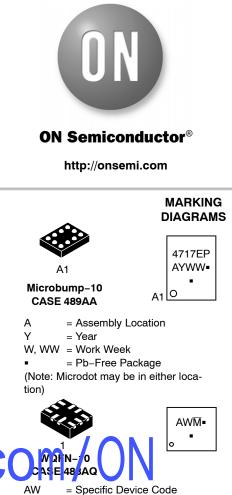
- Cell Phones
- PDAs
- MP3s
- Digital Still Cameras
- USB 2.0 Full Speed (USB1.1) 12 Mbps Compliant

Important Information

- ESD Protection: Human Body Model (HI
 - Human Body Model (HBM) = 2500 V, Machine Model (MM) = 200 V
- Latchup Max Rating: 200 mA (Per JEDEC EIA/JESD78)
- Pin-to-Pin Compatible with MAX4717

*OVT

• Overvoltage Tolerant (OVT) specific pins operate higher than normal supply voltages, with no damage to the devices or to signal integrity.



- \overline{M} = Date Code
 - = Pb-Free Device
- (Note: Microdot may be in either location)

FUNCTION TABLE

IN_	NO_	NC_
0	OFF	ON
1	ON	OFF

ORDERING INFORMATION

Device	Package	Shipping [†]
NLAS4717EPFCT1G	Microbump–10 (Pb–Free)	3000 / Tape & Reel
NLAS4717EPMTR2G	WQFN-10 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

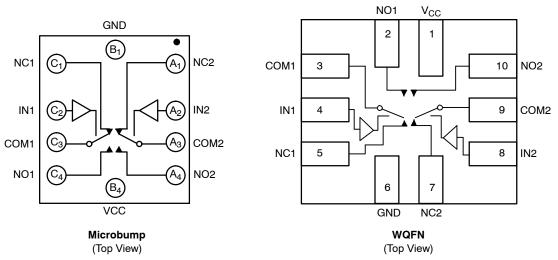


Figure 1. Device Circuit Diagrams and Pin Configurations

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MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V+	DC Supply Voltage	-0.5 to +7.0	V
V _{IS}	Analog Input Voltage (V_{NO} , V_{NC} , or V_{COM}) (Note 1)	$-0.5\leqV_{IS}\leqV_{CC}+0.5$	V
V _{IN}	Digital Select Input Voltage	$-0.5\leqV_{I}\leq+7.0$	V
I _{IK}	DC Current, Into or Out of Any Pin (Continuous)	±100	mA
I _{PK}	Peak Current (10% Duty Cycle)	±200	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Signal voltage on NC, NO, and COM exceeding VCC or GND are clamped by the internal diodes. Limit forward diode current to maximum current rating.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter			Max	Unit
V+	DC Supply Voltage		1.8	5.5	V
V _{IN}	Digital Select Input Voltage		GND	5.5	V
V _{IS}	Analog Input Voltage (NC, NO, COM)		GND	V _{CC}	V
T _A	Operating Temperature Range		-40	+85	°C
t _r , t _f	Input Rise or Fall Time, SELECT $$V_{\rm CC}$ = $V_{\rm CC}$$	= 3.3 V ± 0.3 V = 5.0 V ± 0.5 V	0 0	100 20	ns/V

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ANALOG SWITCH DC CHARACTERISTICS

				-40°C 1	to +85°C	
Symbol	Parameter	Condition	V _{CC} (V)	Min	Мах	Unit
V _{IH}	Input Logic High Voltage	V _{OUT} = 0.1 V	1.65 to 2.2	V _{CC} x 0.55	-	V
		$I_{OUT} \le 20 \ \mu A$	2.7 to 3.6	V _{CC} x 0.5	-	
			4.5 to 5.5	2.0	-	
VIL	Input Logic Low Voltage	V _{OUT} = -V _{CC} - 0.1 V	1.65 to 2.2	_	V _{CC} x 0.2	V
		I _{OUT} ≤ 20 μA	2.7 to 3.6	_	V _{CC} x 0.2	
			4.5 to 5.5	-	0.8	
I _{IN}	Input Leakage Current	$V_{IN} = V_{CC}$ or GND	5.5	-100	+100	nA
V _{CC}	Power Supply Range	All	-	1.65	5.5	V
Icc	Supply Current	V _{IN} = V _{CC} or GND	1.8	_	1.0	μA
		I _{OUT} = 0 μA	3.3	-	1.0	
			5.5	-	1.0	

ANALOG SWITCH CHARACTERISTICS – Digital Section (Voltages Referenced to GND)

					40°C to +85°(C	
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Unit
R _{ON}	ON Resistance (Note 2)	$I_{COM} = 10 \text{ mA}$ $V_{IS} = 0 \text{ to } V_{CC}$	3.0	-	3.2	4.5	Ω
			5.0	-	2.1	3.5	
ΔR _{ON}	ON Resistance Match Between Channels (Note 2 and 3)	I _{COM} = 10 mA V _{IS} = 0 to V _{CC}	3.0	-	0.1	0.4	Ω
	\λ/\λ/\λ/	RDTIC	5 0	hm /	0.1	0.4	
R _{FLAT[ON]}	ON Resistance Flatness (Note 4)	$V_{IS} = 0$ to V_{CC}	3.		2	1.5	Ω
			5.0	-	0.55	1.36	
I _{NO_[OFF]} I _{NC_[OFF]}	NO_, NC_ Off-Leakage Current (Note 5)	$V_{COM} = 0.3 \text{ V or } 3.3 \text{ V}$ $V_{NO} \text{ or } V_{NC} = 0.3 \text{ V or } 3.3 \text{ V}$	3.6	-1.0	0.01	+1.0	nA
		$V_{COM} = 0 \text{ V or } 5.0 \text{ V}$ $V_{NO} \text{ or } V_{NC} = 0 \text{ V or } 5.0 \text{ V}$	5.5	-1.0	0.01	+1.0	
Ісом_[ои]	COM_ On-Leakage Current (Note 5)	$V_{COM} = 0.3 \text{ V or } 3.3 \text{ V}$ $V_{NO} \text{ or } V_{NC} = 0.3 \text{ V or } 3.3 \text{ V}$	3.6	-2.0	0.01	+2.0	nA
		$V_{COM} = 0 V \text{ or } 5.0 V$ $V_{NO} \text{ or } V_{NC} = 0 V \text{ or } 5.0 V$	5.5	-2.0	0.01	+2.0	

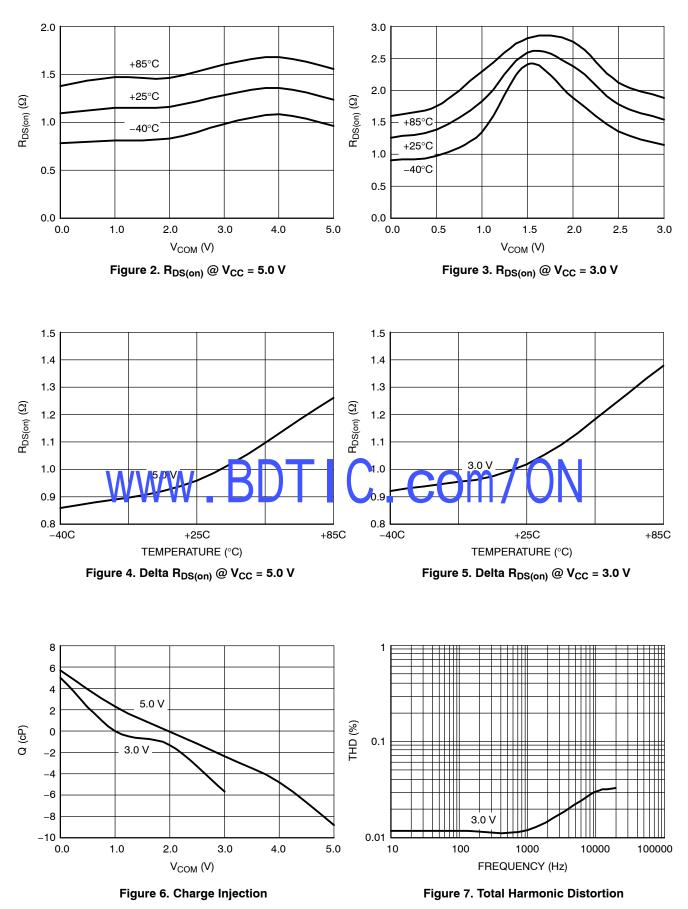
ANALOG SWITCH AC CHARACTERISTICS

				-40°C to +85°C			
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Unit
t _{ON}	Turn-On Time	$ \begin{array}{l} V_{NC_}, V_{NO_} = V_{IH} \text{ or } V_{IL} \\ R_{L} = 300 \; \Omega, \; C_{L} = 35 \; pF \\ V_{IN[X]} = V_{IH} \; or \; V_{IL} \end{array} $	1.8 to 5.5	-	-	30	nS
toff	Turn-Off Time	$ \begin{array}{l} V_{NC_}, V_{NO_} = V_{IH} \text{ or } V_{IL} \\ R_{L} = 300 \ \Omega, \ C_{L} = 35 \ pF \\ V_{IN[X]} = V_{IH} \text{ or } V_{IL} \end{array} $	1.8 to 5.5	-	_	40	nS
^t ввм	Break-Before-Make Time Delay (Note 5)	$V_{NC_{-}}, V_{NO_{-}} = 1.5 \text{ V}$ $R_{L} = 300 \Omega, C_{L} = 35 \text{ pF}$	-	-	8.0	-	nS
t _{SKEW}	Skew (Note 5)	${\sf R}_{\sf S}$ = 39 Ω , ${\sf C}_{\sf L}$ = 50 pF	_	-	0.15	2.0	nS

2. R_{ON} characterized for V_{CC} range (1.65 V to 5.5 V). 3. $\Delta R_{ON} = R_{ON}(MAX) - R_{ON}(MIN)$. 4. $R_{FLAT[ON]} = R_{ON}(MAX) - R_{ON}(MIN)$, measured over V_{CC} range. 5. Guaranteed by design.

ANALOG SWITCH APPLICATION CHARACTERISTICS

				-	40°C to +85°	С	
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Unit
Q	Charge Injection	V _{IN} = V _{CC} to GND	3.0		6.0		рС
		R_{In} = 0 Ω , C_L = 1.0 nF	5.0		9.0		
		$Q = C_L - \Delta V_{OUT}$					
VISO	Off-Isolation	$\label{eq:rescaled} \begin{array}{c} T = 10 \ \mbox{MHz} \\ \mbox{V}_{100}, \ \mbox{V}_{100} = 1.0 \ \mbox{V}_{0} - \mbox{F} \\ \mbox{H}_{1} = 22 \ \mbox{\Omega}, \ \mbox{C}_{1} = 5.0 \ \mbox{pF} \end{array}$	1.65 to 5.5	DM /	-50		dB
		f = 1.0 MHz			-75		
		V _{NO_} , V _{NC_} = 1.0 Vp-p					
		R_L = 50 Ω , C_L = 5.0 pF					
VCT	Cross-Talk	f = 10 MHz	1.65 to 5.5		-80		dB
		V _{NO} , V _{NC} = 1.0 Vp-p					
		$R_L = 50 \Omega$, $C_L = 5.0 pF$					
		f = 1.0 MHz			-110		
		V _{NO} , V _{NC} = 1.0 Vp-p					
		R_L = 50 Ω, C_L = 5.0 pF					
BW	On-Channel	Signal = 0 dB	1.8 to 5.0		90		MHz
	-3.0 db Bandwidth	R_L = 50 Ω , C_L = 5.0 pF					
THD	Total Harmonic Distortion	V_{COM} = 2.0 Vp-p, RL = 600 Ω , T _A = 25°C	-		0.02		%
C _{NO_[OFF]}	NO_, NC_	F = 1.0 MHz	-		15		pF
C _{NC_[OFF]}	OFF-Capacitance						
C _{NO_[ON]}	NO_, NC_	F = 1.0 MHz	-		38		pF
C _{NC_[ON]}	ON-Capacitance						



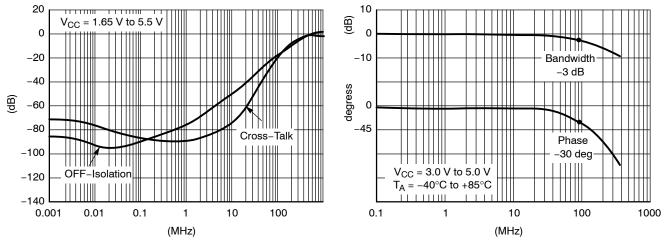
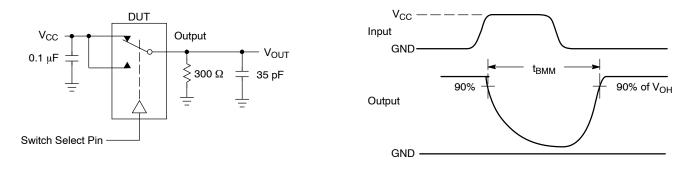


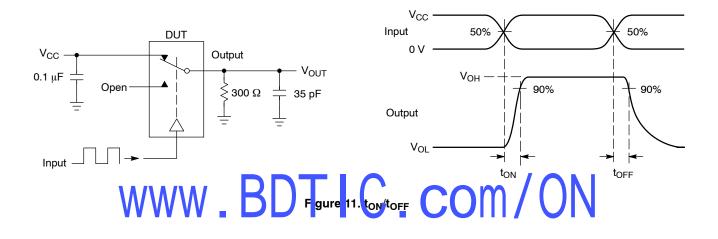


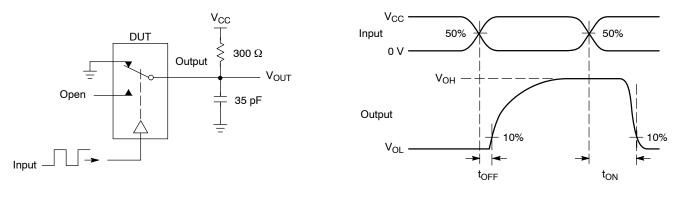
Figure 9. Bandwidth and Phase

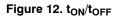
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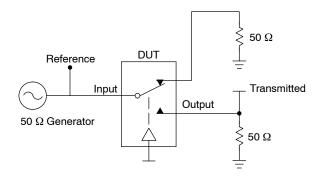








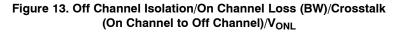




Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch. V_{ISO} , Bandwidth and V_{ONL} are independent of the input signal direction.

$$\begin{split} V_{ISO} &= \text{Off Channel Isolation} = 20 \ \text{Log} \left(\frac{V_{OUT}}{V_{IN}} \right) \ \text{for } V_{IN} \text{ at } 100 \ \text{kHz} \\ V_{ONL} &= \text{On Channel Loss} = 20 \ \text{Log} \left(\frac{V_{OUT}}{V_{IN}} \right) \ \text{for } V_{IN} \text{ at } 100 \ \text{kHz} \text{ to } 50 \ \text{MHz} \end{split}$$

Bandwidth (BW) = the frequency 3.0 dB below V_{ONL} V_{CT} = Use V_{ISO} setup and test to all other switch analog input/outputs terminated with 50 Ω



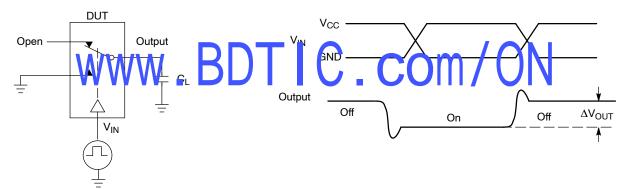
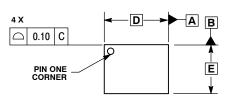
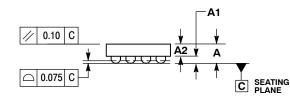


Figure 14. Charge Injection: (Q)

PACKAGE DIMENSIONS

Microbump-10 CASE 489AA-01 **ISSUE A**

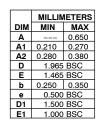


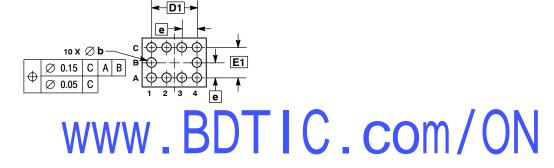


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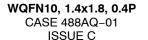
DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
CONTROLLING DIMENSION:

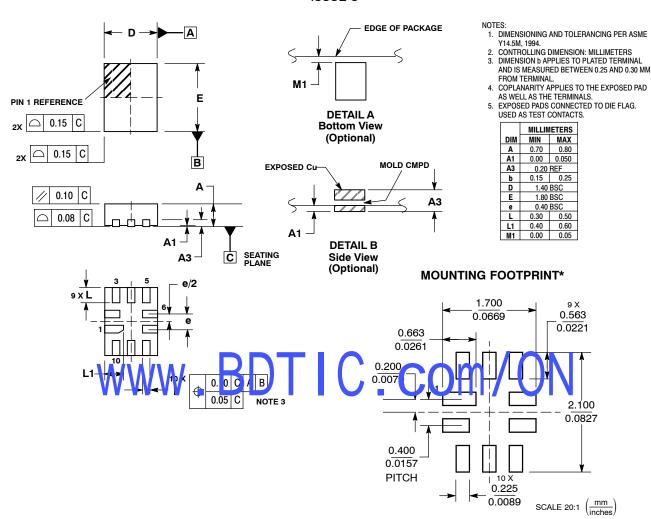
MILLIMETERS. COPLANARITY APPLIES TO SPHERICAL CROWNS OF SOLDER BALLS. З.





PACKAGE DIMENSIONS





*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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